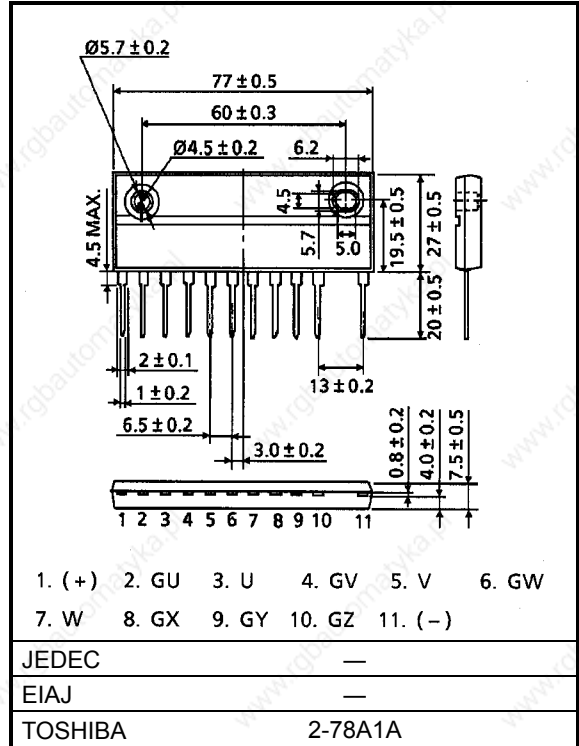


MP6750

High Power Switching Applications
Motor Control Applications

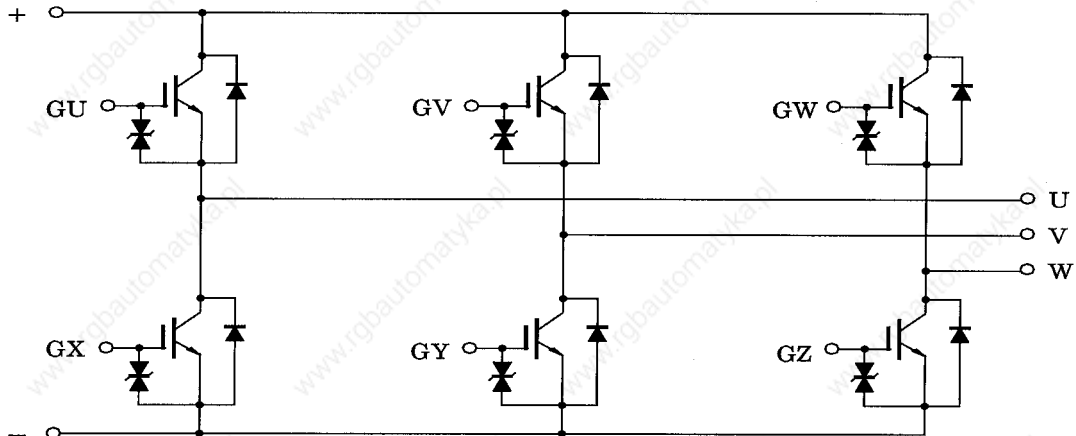
Unit: mm

- The electrodes are isolated from case.
- 6 IGBTs are built into 1 package.
- Enhancement-mode
- Low saturation voltage
: $V_{CE(sat)} = 4.0V$ (Max) ($I_C = 15A$)
- High speed : $t_f = 0.35\mu s$ (Max) ($I_C = 15A$)
 $t_{rr} = 0.15\mu s$ (Max) ($I_F = 15A$)



Weight: 44g

Equivalent Circuit



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• TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..

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Maximum Ratings (Ta = 25°C)

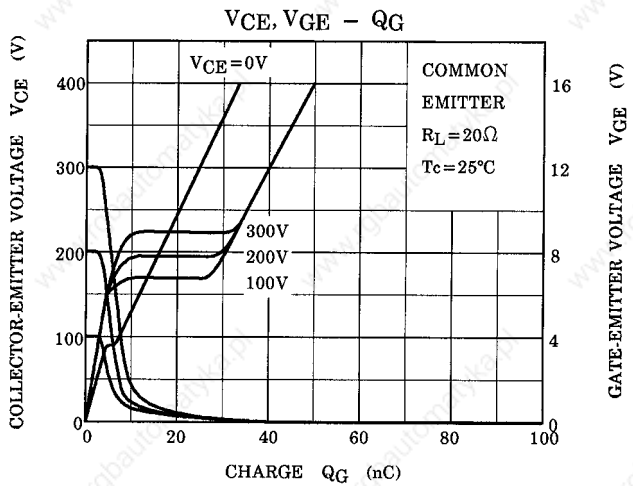
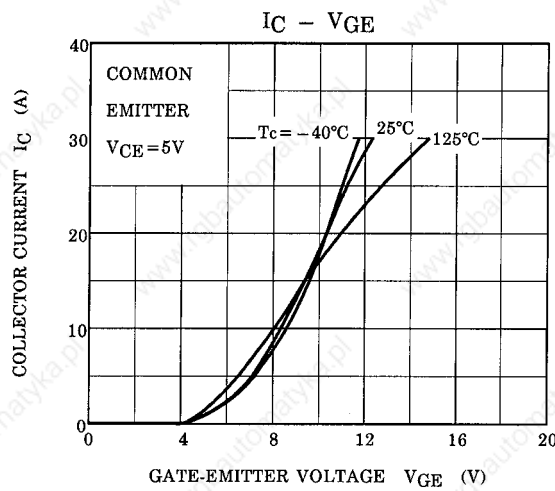
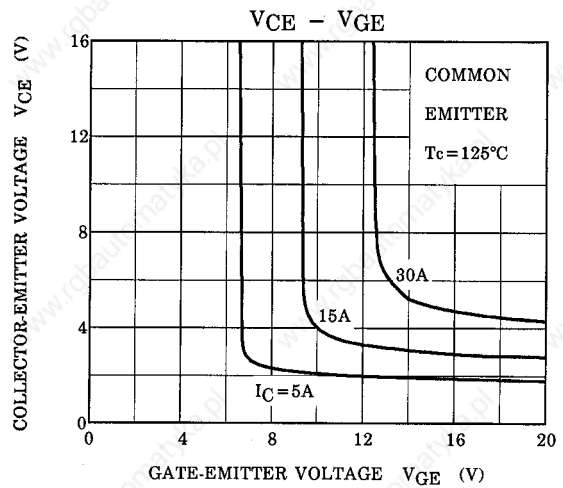
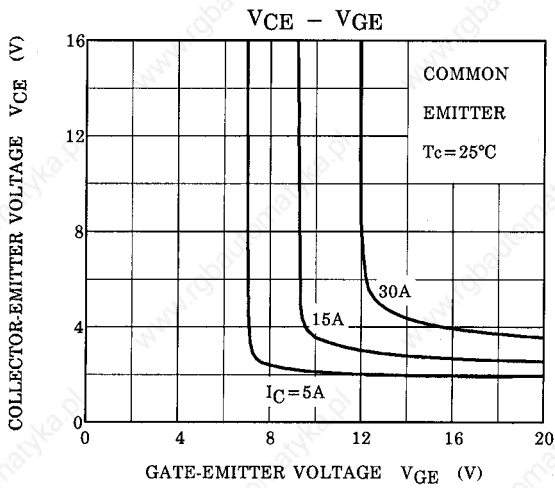
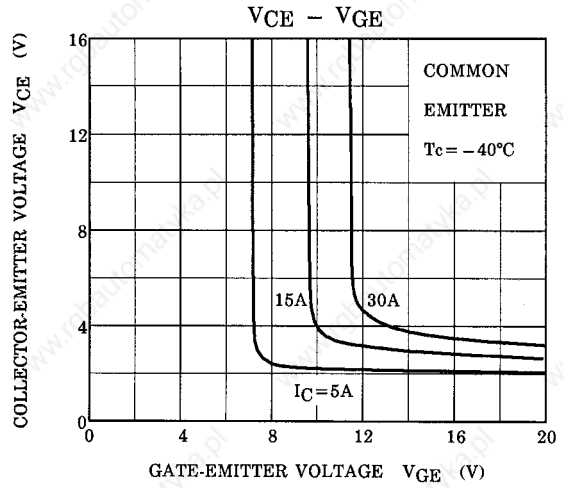
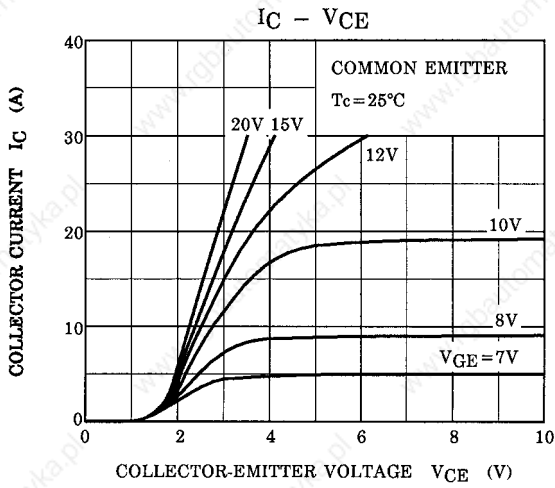
Characteristic		Symbol	Rating	Unit
Collector-emitter voltage		V_{CES}	600	V
Gate-emitter voltage		V_{GES}	± 20	V
Collector current	DC	I_C	15	A
	1ms	I_{CP}	30	
Forward current	DC	I_F	15	A
	1ms	I_{FM}	30	
Collector power dissipation (Tc = 25°C)		P_C	55	W
Junction temperature		T_j	150	°C
Storage temperature range		T_{stg}	-40 ~ 125	°C
Isolation voltage		V_{isol}	2500 (AC 1 minute)	V
Screw torque		—	1.5	N·m

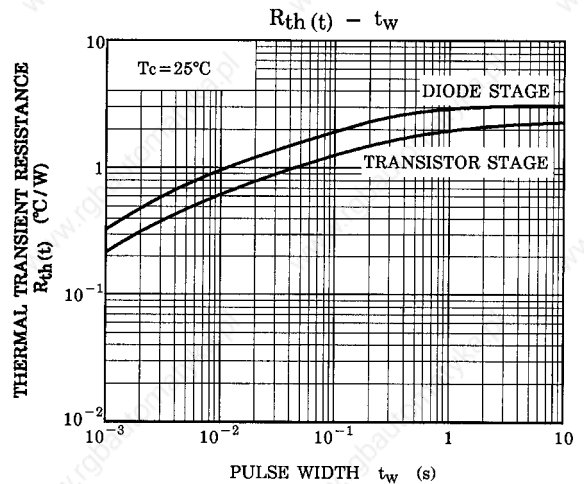
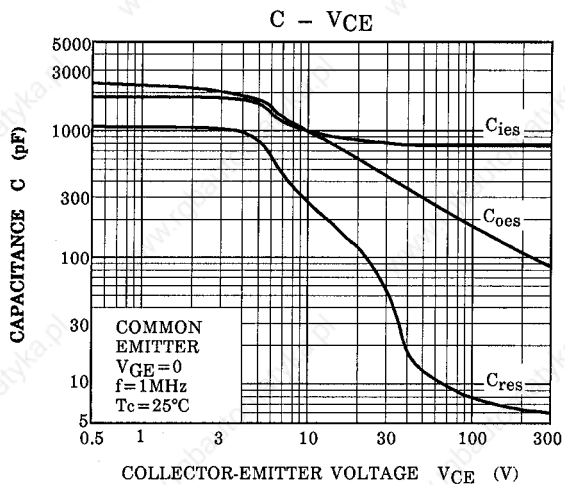
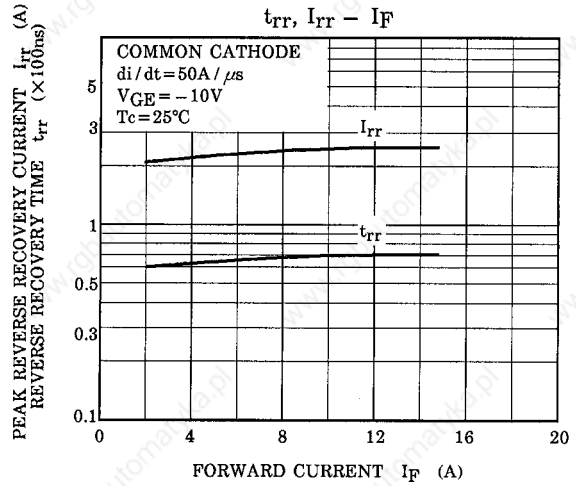
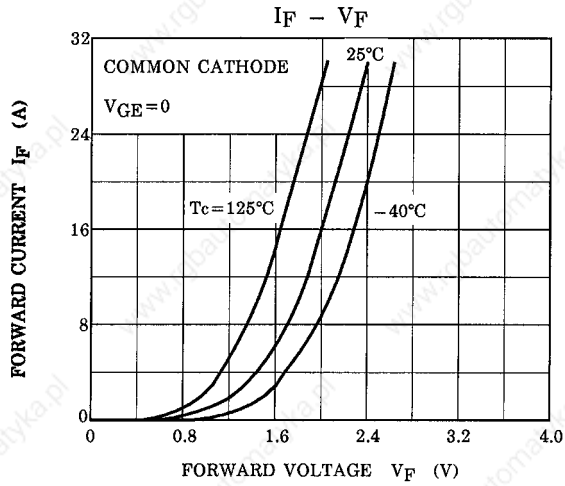
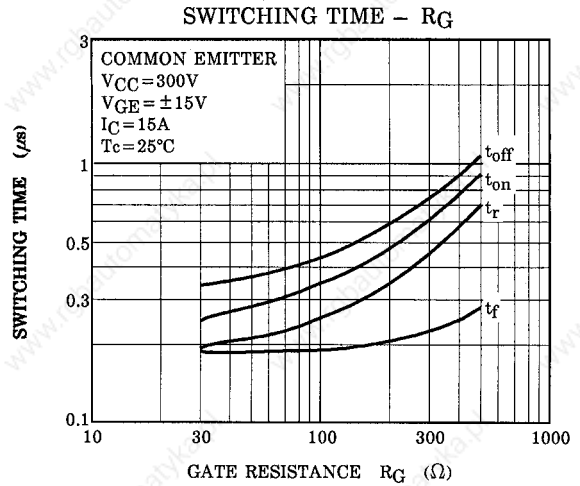
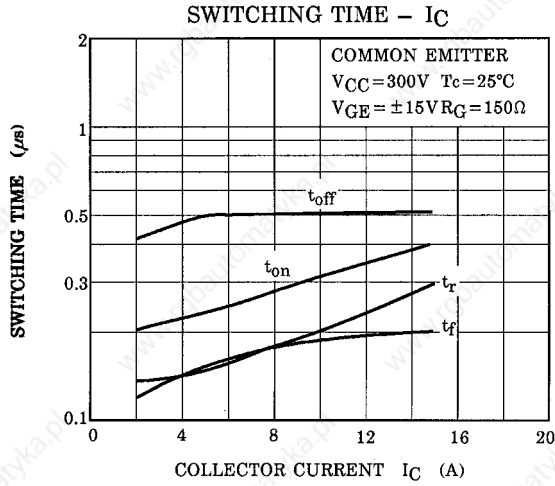
Electrical Characteristics (Ta = 25°C)

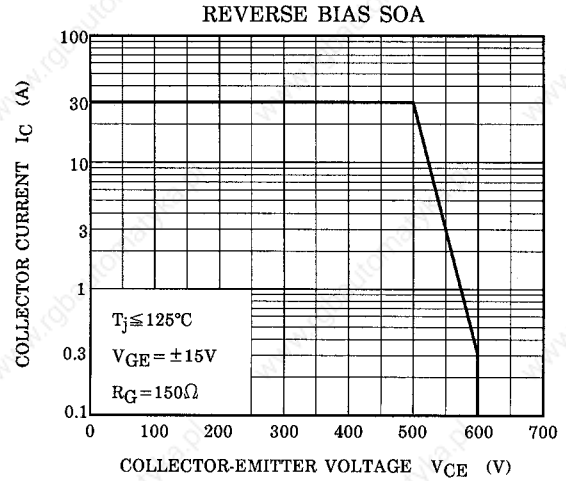
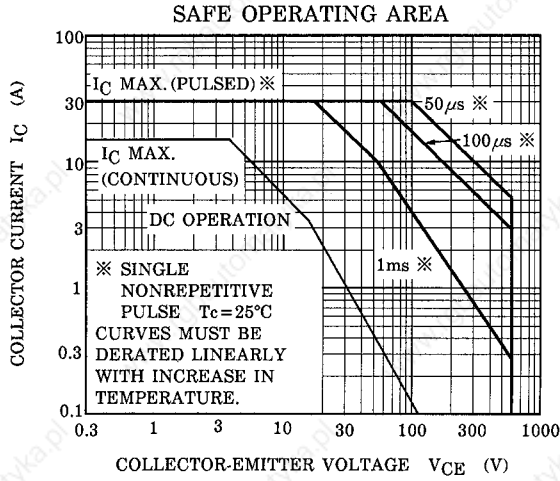
Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		I_{GES}	$V_{GE} = \pm 20V, V_{CE} = 0$	—	—	± 20	μA
Collector cut-off current		I_{CES}	$V_{CE} = 600V, V_{GE} = 0$	—	—	1.0	mA
Gate-emitter cut-off voltage		$V_{GE (off)}$	$I_C = 15mA, V_{CE} = 5V$	3.0	—	6.0	V
Collector-emitter saturation voltage		$V_{CE (sat)}$	$I_C = 15A, V_{GE} = 15V$	—	3.0	4.0	V
Input capacitance		C_{ies}	$V_{CE} = 10V, V_{GE} = 0, f = 1MHz$	—	1000	—	pF
Switching time	Rise time	t_r		—	0.3	0.6	μs
	Turn-on time	t_{on}		—	0.4	0.8	
	Fall time	t_f		—	0.2	0.35	
	Turn-off time	t_{off}		—	0.5	1.0	
Forward voltage		V_F	$I_F = 15A, V_{GE} = 0$	—	1.7	2.5	V
Reverse recovery time		t_{rr}	$I_F = 15A, V_{GE} = -10V$ $di / dt = 50A / \mu s$	—	0.08	0.15	μs
Thermal resistance	$R_{th (j-c)}$	Transistor	—	—	2.27	°C / W	
		Diode	—	—	3.09		

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